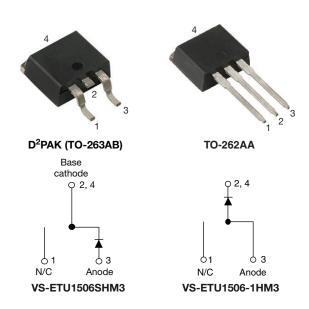
VS-ETU1506SHM3, VS-ETU1506-1HM3

Vishay Semiconductors

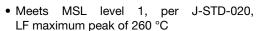
Ultra Fast Rectifier, 15 A FRED Pt®



PRIMARY CHARACTERISTICS				
Package	D ² PAK (TO-263AB), TO-262AA			
I _{F(AV)}	15 A			
V _R	600 V			
V _F at I _F	1.1 V			
t _{rr} (typ.)	24 ns			
T _J max.	175 °C			
Circuit configuration	Single die			

FEATURES

- Low forward voltage drop
- Ultrafast recovery time
- 175 °C operating junction temperature
- · Low leakage current
- AEC-Q101 qualified, meets JESD 201 class 1 whisker test











DESCRIPTION

State of the art, ultralow V_F , soft-switching ultrafast rectifiers optimized for Discontinuous (Critical) Mode (DCM) Power Factor Correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimized the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

APPLICATIONS

AC/DC SMPS 70 W to 400 W

e.g. laptop and printer AC adapters, desktop PC, TV and monitor, games units, and DVD AC/DC power supplies.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Repetitive peak reverse voltage	V_{RRM}		600	V
Average rectified forward current	I _{F(AV)}	T _C = 143 °C	15	۸
Non-repetitive peak surge current	I _{FSM}	T _C = 25 °C	160	A
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA		-	-	
Forward voltage V _F	V	I _F = 15 A	-	1.35	1.9	V
	v _F	I _F = 15 A, T _J = 150 °C	-	1.1	1.3	
Reverse leakage current	_	$V_R = V_R$ rated	-	0.01	15	μA
Reverse leakage current I _R		$T_J = 150 ^{\circ}\text{C}, V_R = V_R \text{rated}$	-	20	200	μΑ
Junction capacitance	C _T	V _R = 600 V	-	12	-	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body - 8.0 -		nH		



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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		ı	-	28	
Reverse recovery time	t _{rr}	T _J = 25 °C	I _F = 15 A dI _F /dt = 200 A/μs V _R = 390 V	1	40	i	ns
		T _J = 125 °C		1	87	i	
Peak recovery current	I _{RRM}	T _J = 25 °C		1	5	-	A C
		T _J = 125 °C		ı	9.0	ı	
Davida da d	0	T _J = 25 °C		1	107	-	
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	430	-	
Reverse recovery time	t _{rr}	T _J = 125 °C	I _F = 15 A dI _F /dt = 800 A/μs V _R = 390 V	-	53	-	ns
Peak recovery current	I _{RRM}			-	25	-	Α
Reverse recovery charge	Q _{rr}			-	730	-	nC

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C
Thermal resistance, junction to case	R _{thJC}		-	-	1.51	°C/W
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	70	
Thermal resistance, case to heat sink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-	
Weight			-	2.0	-	g
Weight			-	0.07	-	oz.
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)
Madanada		Case style D ² PAK	ETU1506SH			•
Marking device		Case style TO-262	ETU1506-1H			

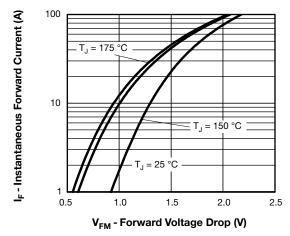


Fig. 1 - Typical Forward Voltage Drop Characteristics

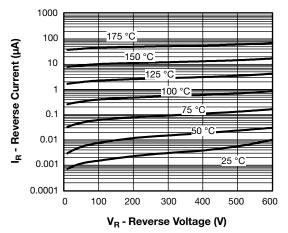


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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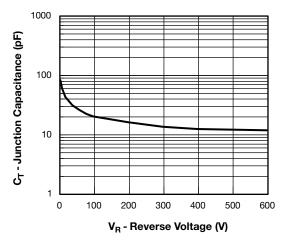


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

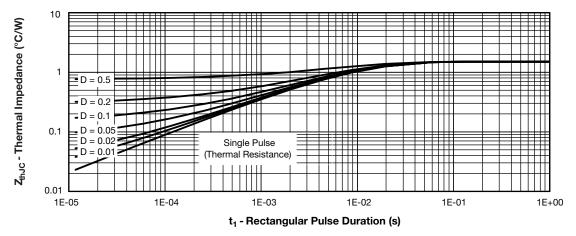


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics

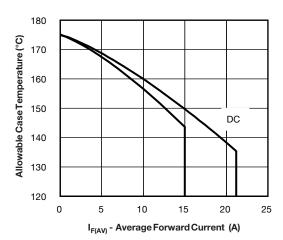


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

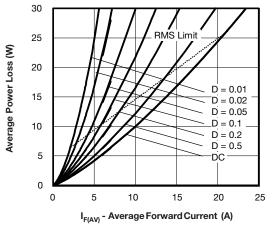


Fig. 6 - Forward Power Loss Characteristics

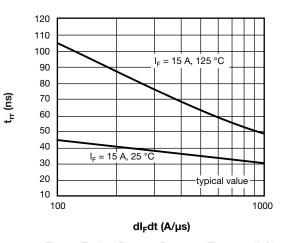


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

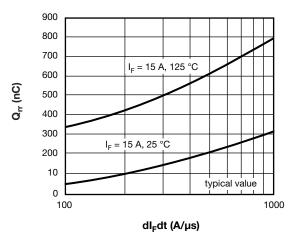
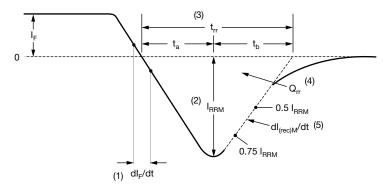


Fig. 8 - Typical Stored Charge vs. dl_F/dt



- (1) dl_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) dl_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

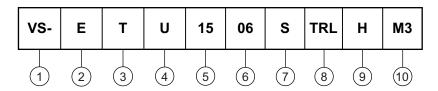
Fig. 9 - Reverse Recovery Waveform and Definitions

VS-ETU1506SHM3, VS-ETU1506-1HM3

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

Circuit configuration
E = single diode

T = TO-220

4 - U = ultrafast recovery time

5 - Current code (15 = 15 A)

Voltage code (06 = 600 V)

7 - •S = D²PAK

- • -1 = TO-262

8 - • None = tube (50 pieces)

TRL = tape and reel (left oriented, for D²PAK package)

- • TRR = tape and reel (right oriented, for D²PAK package)

9 - H = AEC-Q101 qualified

- M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-ETU1506SHM3	50	1000	Antistatic plastic tube		
VS-ETU1506-1HM3	50	1000	Antistatic plastic tube		
VS-ETU1506STRRHM3	800	800	13" diameter reel		
VS-ETU1506STRLHM3	800	800	13" diameter reel		

LINKS TO RELATED DOCUMENTS					
Dimensions	TO-263AB (D ² PAK)	www.vishay.com/doc?95046			
Difficusions	TO-262AA	www.vishay.com/doc?95419			
Part marking information	TO-263AB (D ² PAK)	www.vishay.com/doc?95444			
Fait marking information	TO-262AA	www.vishay.com/doc?95443			
Packaging information	TO-263AB (D ² PAK)	www.vishay.com/doc?95032			
SPICE model		www.vishay.com/doc?96132			



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